

N-Channel Enhancement Mode Field Effect Transistor

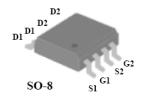
FEATURES

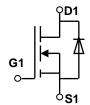
- Super high dense cell design for low RDS(ON)
- Rugged and reliable
- Simple drive requirement
- SOP-8 package

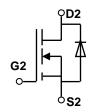
PRODUCT SUMMARY					
V _{DSS}	ID	$RDS(ON)$ $(m \Omega)$ Typ			
20V	6A	22 @ VGS=4.5V			
		35 @ VGS=2.5V			



NOTE: The MT9926 is available in a lead-free package







ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	20	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous ^a @Tj=125℃	ID	6	A
- Pulse d^b	Ідм	20	A
Drain-source Diode Forward Current ^a	Is	1.7	A
Maximum Power Dissipation ^a	PD	2.5	W
Operating Junction and Storage Temperature Range	TJ,Tstg	-55 to 150	${\mathbb C}$

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to Ambient ^a	Rth JA	80	°C/W
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ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS	-		1		l	
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V,Id=250µA	20			V
Zero Gate Voltage Drain Current	IDSS	Vds=16V,Vgs=0V			1	μА
Gate-Body Leakage	Igss	Vgs=±8V,Vds=0V			±100	nA
ON CHARACTERITICS						
Gate Threshold Voltage	V _G s(th)	Vds=Vgs,Id=250µA	0.5	0.8	1.5	V
Drain-Source On-State Resistance	Draway	Vgs=4.5V,Id=6A		22	25	m Ω
	Rds(on)	Vgs=2.5V,Id=2.8A		35	38	
Forward Transconductance	gFS	Vgs=5V,Id=5A		5		S
DAYNAMIC CHARACTERISTICS			•			
Input Capacitance	Ciss	V _{DS} =10V,V _{GS} =0V f=1.0MHz		608		pF
Output Capacitance	Coss			115		pF
Reverse Transfer Capacitance	Crss			86		pF
SWITCHING CHARACTERISISTICS			•			
Turn-On Delay Time	td(ON)	VDD=10V ID=6A, VGEN=4.5V RL=10ohm RGEN=10ohm		10		ns
Rise Time	tr			14		ns
Turn-Off Delay Time	tD(OFF)			39		ns
Fall Time	tf			26		ns
Total Gate Charge	Q g	VDS=10V,ID=1A VGS=4.5V		9.2		nC
Gate-Source Charge	Qgs			1.6		nC
Gate-Drain Charge	Qgd			2.6		nC

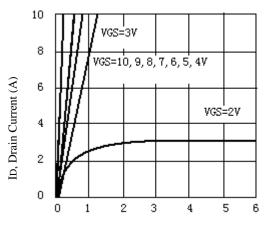


ELECTRICAL CHARACTERICS (TA=25°C unless otherwise noted)

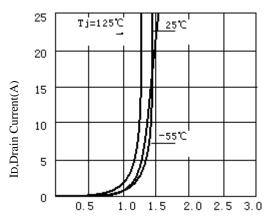
Parameter	Symbol	Condition	Min	Тур	Max	Unit	
DRAIN-SOURCE DIODE CHARACTERISTICS							
Diode Forward Voltage	Vsd	Vgs=0V,Is=1.7A		0.84	1.3	V	

Notes

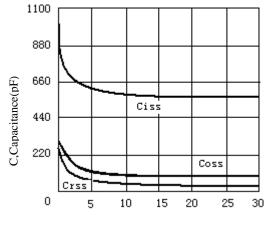
- a. Surface Mounted on FR4 Board, t ≤ 10sec
- b. Pulse Test: Pulse Width ≤ 300Us, Duty Cycle ≤ 2%
- c. Guaranteed by design, not subject to production testing.



VDS, Drain-to-Source Voltage (V) Figure 1. Output Characteristics



VGS, Gate-to-source Voltage (V) Figure 2. Transfer Characteristics



VGS, Drain-to Source Voltage Figure3. Capacitance

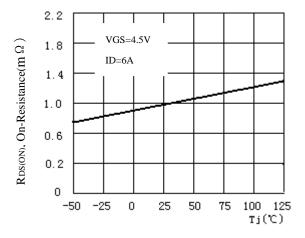
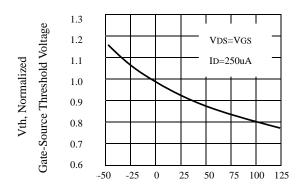
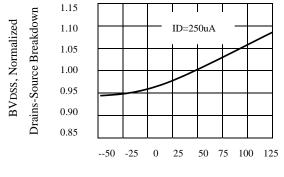


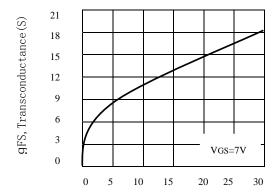
Figure 4. On-Resistance Variation with Temperature



 $\label{eq:Tj.Junction} Temperature({}^{\circ}\mathbb{C})$ Figure 5. Gate Threshold Variation With Temperature



Tj, Junction Temperature ($^{\circ}$ C) Figure 6. Breakdown Voltage Variation With Temperature



IDS, Drain-Source Current (A)
Figure 7. Transconductance Variation
With Drain Current

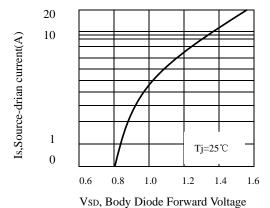


Figure 8. Body Diode Forward Voltage
Variation with Source Current

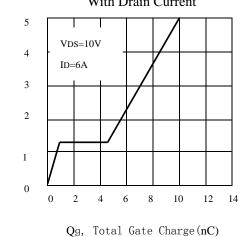
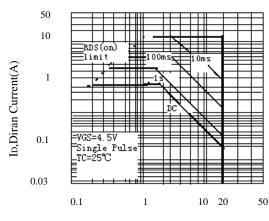


Figure 9. Gate Charge



VDS, Drain-Source Voltage(V)
Figure 10.Maximum Safe Operating Area

VGS, Gate to Source Voltage

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